EXHIBIT B

ASSIGNMENT

WHEREAS, Princeton Lightwave, Inc. ASSIGNOR, a Delaware corporation, is the owner of the entire right, title, and interest in the patents and patent applications listed on Schedule I attached hereto (collectively referred to as the "Previously Assigned Patents and Patent Applications"), subject to the May 2000 License Agreement (as defined below);

WHEREAS, The Sarnoff Corporation, a Delaware corporation ("Sarnoff Delaware"), and ASSIGNOR, pursuant to a TECHNOLOGY AND PATENT LICENSE AGREEMENT executed by Sarnoff New Jersey and ASSIGNOR and dated May 5, 2000 and an AMENDMENT TO TECHNOLOGY AND PATENT LICENSE AGREEMENT executed by Sarnoff New Jersey and ASSIGNOR and dated July 18, 2002 (collectively the "May 2000 License Agreement"), previously entered into assignments of the Previously Assigned Patents and Patent Applications;

WHEREAS, Sarnoff Corporation, a New Jersey corporation ("Sarnoff New Jersey"), possessed a legal interest in the Previously Assigned Patents and Patent Applications;

WHEREAS, the parties intend to ensure the proper assignment of the Previously Assigned Patents and Patent Applications such that Trumpf Photonics, Inc., ASSIGNEE, a Delaware corporation, may acquire the entire right, title, and interest in, to and under the Previously Assigned Patents and Patent Applications;

WHEREAS, in order to ensure such proper assignment, by separate written agreement Sarnoff New Jersey assigned to ASSIGNOR the entire, right, title, and interest in, to and under the Previously Assigned Patents and Patent Applications, subject to the May 2000 License Agreement;

WHEREAS, ASSIGNEE is desirous of obtaining the entire right, title and interest in, to and under the Previously Assigned Patents and Patent Applications, subject to the May 2000 License Agreement;

AND WHEREAS, it is desired that the assignment of these Previously Assigned Patents and Patent Applications be made a matter of record in the appropriate domestic and international patent offices;

NOW, THEREFORE, for good and valuable consideration, receipt of which is hereby acknowledged, PLI hereby assigns and transfers unto Trumpf and its successors and assigns, the entire right, title and interest in and to the Previously Assigned Patents and Patent Applications (including the inventions disclosed therein and any divisions, continuations, reissues, reexaminations, extensions or foreign counterparts thereof) together with all rights of action and recovery for past infringement thereof, subject to the May 2000 License Agreement;

AND ASSIGNOR HEREBY authorizes and requests the Commissioner of Patents and Trademarks of the United States, and any Official of any country or countries foreign to the United States, whose duty it is to issue patents or other evidence or forms of industrial property protection on applications as aforesaid, to issue the same to the said ASSIGNEE, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

AND ASSIGNOR HEREBY further covenants and agrees that ASSIGNOR shall execute and deliver such documents and take such actions, at ASSIGNEE's expense, as are reasonably necessary or appropriate to effect this assignment of the Previously Assigned Patents and Patent Applications.

[PAGE BELOW INTENTIONALLY LEFT BLANK, SIGNATURE PAGE TO FOLLOW]

IN TESTIMONY WHEREOF, each party has caused its authorized representative to execute this Assignment (Exhibit B) as of 3043, 2002 (the "Effective Date").

PRINC	ETON LIGHTWAVE, INC.	TRUMPF PHOTONICS, INC.	
Вү	Cetann	BY	
Name	Didier Le Lannic	Name	
Title	President and Chief	Title	
1100	Executive Officer		

[SIGNATURE PAGE TO EXHIBIT B -ASSIGNMENT AND COVENANT NOT TO SUE AGREEMENT]

IN TESTIMONY WHEREOF, each party has caused its authorized representative to execute this Assignment (Exhibit B) as of 304 12,2002 (the "Effective Date").

PRINCETON LIGHTWAVE, INC.	TRUMPF PHOTONICS, INC.
BY	BY Veter tu
Name	Name Peter Leibinger
Title	Title President

[SIGNATURE PAGE TO EXHIBIT B -ASSIGNMENT AND COVENANT NOT TO SUE AGREEMENT]

SCHEDULE 1 TO EXHIBIT B OF ASSIGNMENT AND COVENANT NOT TO SUE AGREEMENT (Previously Assigned Patents and Patent Applications)

TITLE	INVENTORS	PATENT OR PUB NO.	APPLICATION NO.	FILING DATE	ISSUE DATE	PLI CASE NO.
Monolithic Semiconductor Light Emitter and Amplifier	Carlson	US 5,131,001	07/632,263	12/21/1990	7/14/1992	10579
High Power Semiconductor	Abeles,	US 5,818,860	08/757,883	11/27/1996	10/6/1998	11611
Laser Diode	Connolly, Garbuzov	JP 10-303500	9-363805	11/27/1997		11011
Semiconductor Distributed	Abeles,	US 5,619,523	08/524,956	9/8/1995	DATE 7/14/1992 6 10/6/1998 7 4/8/1997 7 3/7/2000 8 NA 9 O	11698
Feedback Laser Diode	Connolly, Morris	WO 97/09760	PCT/US96/13820	9/9/1996		
Electroluminescent with Diode Mode Expander		US 6,034,380	08/946,180	10/7/1997	3/7/2000	11961
Electroluminescent with Diode Mode Expander	Alphonse, Andrews, Menna	CA 2245399	2245399	8/20/1998		11961 CA
Semiconductor Diode	l limit was, ivienia	EP 908959	98307504.5	9/16/1998		11961 EP
Electroluminescent with Diode Mode Expander		JP 11-214745	10-285363	10/7/1998		11961 ЈР
Will Got Dischard	G	US Prov	: 60/133,393	5/10/1999	NA	
Monolithic Semiconductor Light Emitter and Amplifier High Power Semiconductor Laser Diode Semiconductor Distributed Feedback Laser Diode Electroluminescent with Diode Mode Expander Electroluminescent with Diode Mode Expander Semiconductor Diode Electroluminescent with	Connolly, DiMarco, Garbuzov, Khalfin	US App	· 09/468,396	12/20/1999		12709
		AU 7049800	200070498	5/10/2000		
opecaar Characteriones		WO 00/72409	PCT/US00/12600	5/10/2000		12709
	Connolly,	US App	09/546,086	4/10/2000	Allowed	12709A
Electroluminescent with Diode Mode Expander Electroluminescent with Diode Mode Expander Electroluminescent with Diode Mode Expander Semiconductor Diode Electroluminescent with Diode Mode Expander Wide Stripe Distributed Bragg Reflector Lasers with Improved Angular and Spectral Characteristics Master Oscillator Granting Coupled Power Amplifier with Angled Amplifier Section High Power Semiconductor	DiMarco, Garbuzov,	AU 7049900	200070499	5/10/2000		
	Khalfin	WO 00/72450	PCT/US00/12708	5/10/2000		12709A
		US Prov	60/089,454	6/16/1998	NA	
,	Alphonse	US 6,339,606	09/158,847	9/23/1998	1/15/2002	12797
		EP 1121720	99928706.3	6/16/1999		12797 EP
Light Source		JР	2000-555342	6/16/1999		12797 ЈР
Light Source		WO 99/66613	PCT/US99/13568	6/16/1999		12797 PCT

TITLE	INVENTORS	PATENT OR PUB NO.	APPLICATION NO.	FILING DATE	ISSUE DATE	PLI CASE NO.
Mode Matching in Super Luminescent Diode Cavities	Burstyn, Shapiro, Riddle, Lurie	US Prov	60/132,791	5/6/1999	NA	12977
Mode Matching in Super Luminescent Diode Cavities Phase Conjugating Structure for Mode Matching in Super Luminescent Diode Cavities	Burstyn [Shapiro, Riddle, Lurie]	US App	09/566,276	5/5/2000		12977
	Burstyn	AU 4831200	200048312	5/8/2000		
	Burstyn	WO 00/68720	PCT/US00/12635	5/6/1999 NA 5/6/1999 NA 5/5/2000 5/8/2000 635 5/8/2000 635 5/8/2000 6311/10/2000 63 11/10/2000 63 11/10/2000 63 10/29/1999 10/9/2001 63 4/17/2000 63 4/17/2000 63 4/17/2000 63 10/22/1999 NA 65 5/16/2000 63 10/23/2000 64 10/23/2000 65 10/23/2000	12977 PCT	
		US Prov	60/164,864	11/12/1999	DATE NA	
Current Spreading in Semiconductor Laser Diodes	Connolly,	US App	09/710,362	11/10/2000		13206
	DiMarco	AU 1762601	200117626	11/10/2000		15200
		WO 01/35506	PCT/US00/31048	11/10/2000]
	Maiorov, Khalfin,	US Prov	60/129810	4/16/99		
		US 6,301,279	09/430,643	10/29/1999	10/9/2001	13505
		AU 6888000	200068880	4/17/2000		
		CA	2370788	4/17/2000		13505 CA
of the Active Region		EP	00957229.8	4/17/2000		13505 EP
Temperature	Conrolly	EP 1173907		4/17/2000	DATE NA	
		WO 00/65699	PCT/US00/10294	4/17/2000		13505 PCT
		US Prov	60/161,213	10/22/1999) 10/9/2001 NA 3/26/2002	13764
	Alphose	US App	09/571,970	5/16/2000		13764
Integrated High Power		AU 4503301	200145033	10/23/2000		
Semiconductor Laser		TW	89122242	10/23/2000		13764 - TW
₩		WO 01/39341	PCT/US00/41425	10/23/2000		13764 PCT
	AU 2299201 200122992 10 Alphose TW 89122242 10	5/16/2000	3/26/2002	13764A		
		AU 2299201	200122992	10/23/2000		,
		TW	89122242	10/23/2000		13764A TW
		WO 01/29590	PCT/US00/41417	10/23/2000		13764A PCT
	Garbuəv, Khalfı,	US Prov	60/176,909	1/20/2000	. NA	
Current Spreading in Semiconductor Laser Diodes Control of Current Spreading in Semiconductor Laser Diodes Semiconductor Diode Lasers with Thermal Sensor Control of the Active Region Temperature Integrated High Power Semiconductor Laser Mode Expander with Co-Directional Grating Semiconductor Diode Lasers		US App	09/553,551	4/20/2000		13858

TITLE	INVENTORS	PATENT OR PUB NO.	APPLICATION NO.	FILING DATE	ISSUE DATE	PLI CASE NO.
Divergence	Connolly	WO 01/57974	PCT/US01/01971	1/19/2001		13858 PCT
	Garbuzov, Khalfin	US Prov	60/176,913	1/20/2000	NA	13860
High-Power Single Mode Semiconductor Laser Diode		US App	09/585,032	6/1/2000		
\		WO 01/57973	PCT/US01/01970	1/19/2001		
Channelizer Switch**	· .	US Prov	60/176,915	1/20/2000	NA	13869
High Power Distributed	Abeles	AU 4719201	200147192	1/22/2001		13870
Feedback Ridge Waveguide Laser		WO 01/54240	PCT/US01/02019	1/22/2001	-	13870
Double-Pass High Power Superluminescent Diode (SLD) And Optical Amplifier with Mode Stabilization	Alphonse	US Prov	60/185,133	2/25/2000	NA	13922
Multi-Pass, Arcuate Bent Waveguide, High Power Superluminescent Diode		WO 01/63331	PCT/US01/06039	2/23/2001		13922

^{**}Inventions in this provisional will be assigned only to the extent that Case No. 13870 claims priority of an invention in the provisional.